

TECHNICAL DATA DATA SHEET 4627, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 200 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ Tc = 25 °C UNLESS OTHERWISE SPECIFIED.

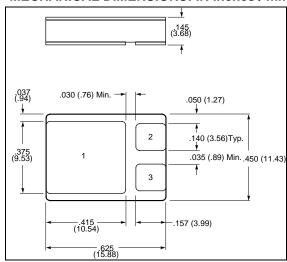
MAXIMOM IX TINGS	ALL RATINGS ARE @ 1 _C = 25 C UNLESS OTHERWISE SPECIFIED.				
RATING	SYMBOL	MAX.	UNITS		
PEAK INVERSE VOLTAGE	PIV	200	Volts		
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_C =100 $^{\circ}$ C) (Single)	Io	30	Amps		
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps		
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	Ст	600	pF		
MAXIMUM THERMAL RESISTANCE	$R_{ heta JC}$	0.61	°C/W		
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE		-65 to + 200	°C		

ELECTRICAL CHARACTERISTICS

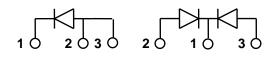
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 30 Amps)			
T _J = 25 °C	V_{f}	1.01	Volts
T _J = 125 °C		0.85	
MAXIMUM REVERSE CURRENT (I _r @ 200 V PIV)			
T _J = 25 °C	l _r	0.7	mA
T _J = 125 °C		16	

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MECHANICAL DIMENSIONS: IN Inches / mm





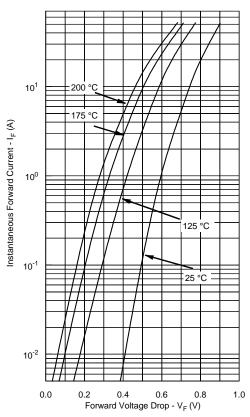


LCC-3P

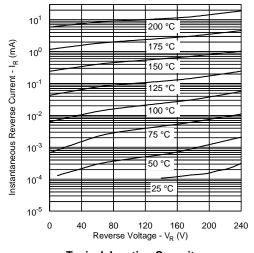
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

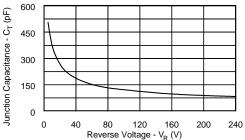




Typical Reverse Characteristics



Typical Junction Capacitance





TECHNICAL DATA

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